



Micro Commercial Components

Micro Commercial Components  
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# MJ431

## 10 Amp NPN Silicon Power Transistors 125W

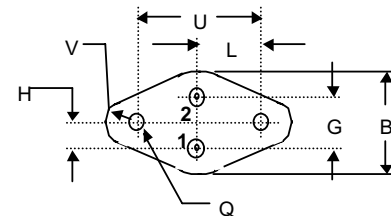
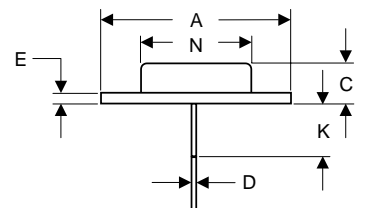
### Features

- Collector-Emitter Voltage:  $V_{CEX}=400V(\text{Min})$
- DC Current Gain:  $h_{FE}=15-35@ I_C=2.5A$

### Maximum Ratings

Characteristic	Symbol	Max	Unit
Collector-Emitter Voltage	$V_{CEX}$	400	Vdc
Collector-Base Voltage	$V_{CBO}$	400	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	Vdc
Collector Current-Continuous	$I_C$	10	Adc
Base Current	$I_B$	2.0	Adc
Total Device Dissipation @ $T_C=25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	125 1.0	Watts W/ $^\circ\text{C}$
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65~200	$^\circ\text{C}$

### TO-3



PIN 1. BASE  
 PIN 2. EMITTER  
 CASE. COLLECTOR

DIM	INCHES		MM		NOTE
	MIN	MAX REF	MIN	MAX REF	
A	1.550		39.37		
B	0.99	1.050	25.30	26.67	
C	.366	.437	9.30	11.10	
D	.035	.043	0.90	1.10	
E	0.11	0.12	2.90	3.10	
G	.430	BSC	10.92	BSC	
H	.215	BSC	5.46	BSC	
K	.449	.532	11.40	13.50	
L	.659	.671	16.75	17.05	
N	.764	.772	19.40	19.62	
Q	.157	.165	4.00	4.20	∅
U	1.18	1.19	30.00	30.20	
V	.169	.177	4.30	4.50	

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## Electrical Characteristics @ 25°C Unless Otherwise Specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	$I_C = 100\text{mA}; I_B = 0$	325			V
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 2.5\text{A}; I_B = 0.5\text{A}$			0.7	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 2.5\text{A}; I_B = 0.5\text{A}$			1.5	V
$I_{CEX}$	Collector Cutoff Current	$V_{CE}=400\text{V}; V_{BE(off)}=1.5\text{V}$ $V_{CE}=400\text{V}; V_{BE(off)}=1.5\text{V}; T_C=125^\circ\text{C}$			2.5 5.0	mA
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 5\text{V}; I_C = 0$			2.0	mA
$h_{FE-1}$	DC Current Gain	$I_C = 2.5\text{A}; V_{CE} = 5\text{V}$	15		35	
$h_{FE-2}$	DC Current Gain	$I_C = 3\text{A}; V_{CE} = 5\text{V}$	10			
$f_T$	Current Gain-Bandwidth Product	$I_C = 0.2\text{A}; V_{CE} = 10\text{V}; f_{test} = 1\text{MHz}$	2.5			

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Revision: 2

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2008/01/09



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## Ordering Information

Device	Packing
(Part Number)-BP	Bulk;250pcs/Box

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